International

SCHOTTKY RECTIFIER

MBRD650CT MBRD660CT

6 Amp

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I_{F(AV)} = 6.0Amp
V_R = 50-60V
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Major Ratings and Characteristics

Charact	eristics	Values	Units
I (AV)	tangular eform	6	A
V _{RRM}		50-60	V
I _{FSM} @ t	o=5µs sine	490	А
	Apk, T _J = 125°C leg)	0.65	V
T _J rang	je	- 40 to 150	°C

Description/Features

The MBRD650CT, MBRD660CT surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Popular D-PAK outline
- Center tap configuration
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability



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MBRD650CT, MBRD660CT

Bulletin PD-20755 rev. E 05/06

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Voltage Ratings

Part number	MBRD650CT	MBRD660CT
V _R Max. DC Reverse Voltage (V)	50	60
V _{RWM} Max. Working Peak Reverse Voltage (V)		

Absolute Maximum Ratings

	Parameters	Value	Units	Conditions	
I _{F(AV)}	Max. Average Forward (Per Leg)	3.0	Α	50% duty cycle @ T _c = 128°C, r	ectangular wave form
	Current * See Fig. 5 (Per Device)	6			
I _{FSM}	Max. Peak One Cycle Non-Repetitive	490	Α	5µs Sine or 3µs Rect. pulse	Following any rated load condition and with
	Surge Current * See Fig. 7	75	A	10ms Sine or 6ms Rect. pulse	rated V _{RRM} applied
E _{AS}	Non-Repet. Aval. Energy (Per Leg)	6	mJ	T _J = 25 °C, I _{AS} = 1 Amp, L = 12 n	nH
I _{AR}	Repetitive Avalanche Current (Per Leg)	0.6	A	Current decaying linearly to zern Frequency limited by T_J max. V	

Electrical Specifications

	Parameters	Value	Units	C	Conditions
V _{FM}	Max. Forward Voltage Drop	0.7	V	@ 3A	T_= 25 °C
	(Per Leg) * See Fig. 1 (1)	0.9	V	@ 6A	1 _J = 20 0
		0.65	V	@ 3A	T = 105 °C
		0.85	V	@ 6A	T _J = 125 °C
I _{RM}	Max. Reverse Leakage Current	0.1	mA	T _J = 25 °C	V_{p} = rated V_{p}
	(Per Leg) * See Fig. 2 (1)	15	mA	T _J = 125 °C	V _R - lated V _R
CT	Typ. Junction Capacitance (Per Leg)	145	pF	$V_{R} = 5V_{DC}$ (te	est signal range 100Khz to 1Mhz) 25°C
Ls	Typical Series Inductance (Per Leg)	5.0	nH	Measured lea	ad to lead 5mm from package body
dv/dt	Max. Voltage Rate of Change	10000	V/µs	(Rated V _R)	

(1) Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications

	Parameters		Value	Units	Conditions
TJ	Max. Junction Temperatur	eRange (*)	-40 to 150	°C	
T _{stg}	Max. Storage Temperatur	e Range	-40 to 150	°C	
R _{thJC}	Max. Thermal Resistance	(Per Leg)	6	°C/W	DC operation * See Fig. 4
	Junction to Case	(Per Device)	3	1	
R _{thJA}	Max. Thermal Resistance J	lunction	80	°C/W	
	to Ambient				
wt	Approximate Weight		0.3 (0.01)	g (oz.)	
	Case Style		D-Pa	k	Similar to TO-252AA
	Device Marking		MBRD66	50CT	
(*) dP	tot 1				

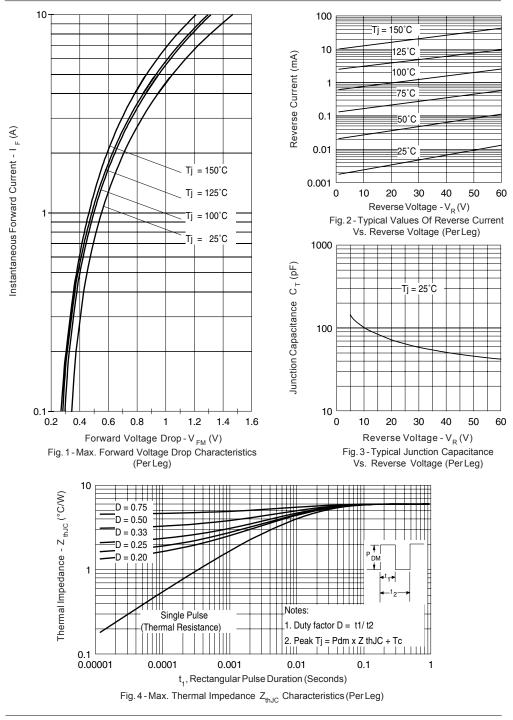
 $\int \frac{dr(dt)}{dT_j} < \frac{1}{Rth(j-a)}$ thermal runaway condition for a diode on its own heatsink

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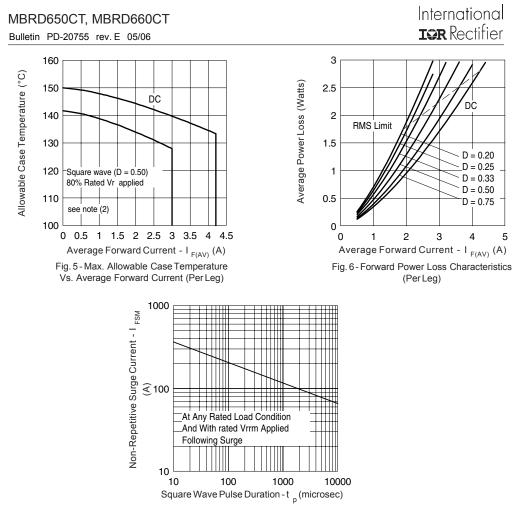
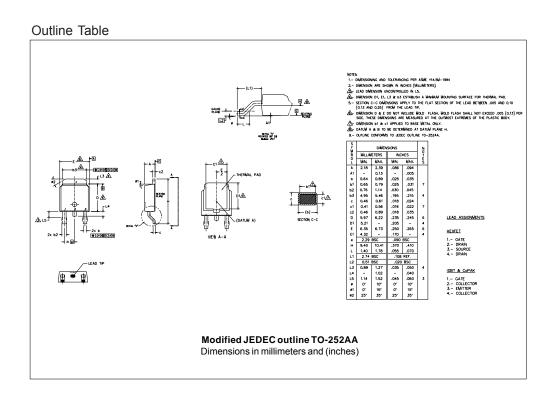


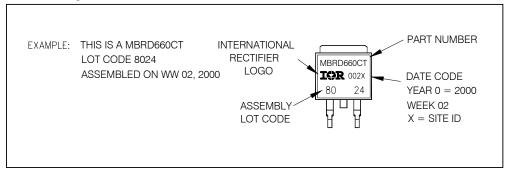
Fig. 7 - Max. Non-Repetitive Surge Current (PerLeg)

(2) Formula used: $T_{c}=T_{J}-(Pd+Pd_{REV}) \times R_{thJC}$; Pd=Forward PowerLoss= $I_{F(AV)} \times V_{FM} @ (I_{F(AV)}/D)$ (see Fig. 6); Pd_{REV}=Inverse PowerLoss= $V_{R1} \times I_{R}(1-D)$; $I_{R} @ V_{R1}=80\%$ rated V_{R}

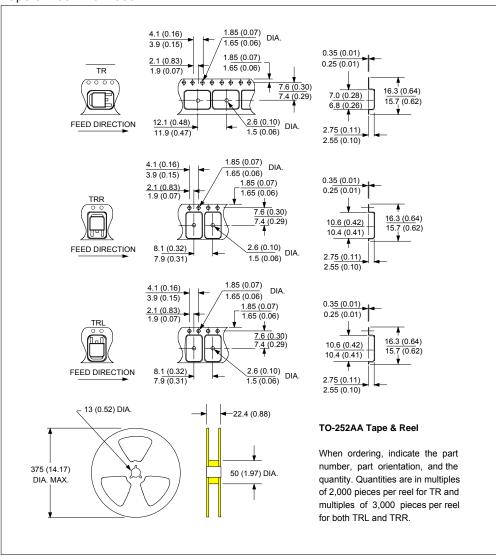
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Part Marking Information



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Tape & Reel Information

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Device Code	MBR	D	6	60	СТ	TR	-
	1	2	3	4	5	6	7
		- Sc	hottky N	MBR Se	ries		
			= D-Pak		,		
			Irrrent F		6 = 6A)		50 = 50
			ltage R	0			60 = 60
		- CT	= Cent	ter Tap	(Dual)		
	6	- •r	none = 1	Tube (5	0 pieces	s)	
		• 7	rR = Ta	pe & Re	eel		
		• 1	rrl =	Tape &	Reel (L	.eft Orie	ented)
		• 1	rrr =	Tape &	Reel (F	Right Or	iented)
	7	- • r	none = S	Standar	d Produ	iction	
		• F	PbF = L	ead-Fre	ee		

Ordering Information Table

Data and specifications subject to change without notice. This product has been designed and qualified for AEC Q101 Level. Qualification Standards can be found on IR's Web site.



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